

60 V, N-channel Trench MOSFET

8 April 2021

Product data sheet

1. General description

N-channel enhancement mode Field-Effect Transistor (FET) in a small SOT457 (SC-74) Surface-Mounted Device (SMD) plastic package using Trench MOSFET technology.

2. Features and benefits

- Very fast switching
- Extended temperature range T_i = 175 °C
- Trench MOSFET technology
- AEC-Q101 qualified

3. Applications

- Relay driver
- High-speed line driver
- Low-side load switch
- Switching circuits

4. Quick reference data

Table 1. Quick reference data

Table II dalen							
Symbol	Parameter	Conditions		Min	Тур	Мах	Unit
V _{DS}	drain-source voltage	T _j = 25 °C		-	-	60	V
V _{GS}	gate-source voltage			-20	-	20	V
I _D	drain current	V _{GS} = 10 V; T _{amb} = 25 °C	[1]	-	-	4.7	А
Static characte	eristics						·
R _{DSon}	drain-source on-state resistance	V _{GS} = 10 V; I _D = 4.7 A; T _j = 25 °C		-	29	36	mΩ

[1] Device mounted on an FR4 Printed-Circuit Board (PCB), single-sided copper, tin-plated and mounting pad for drain 6 cm².



5. Pinning information

Table 2	2. Pinning info	ormation		
Pin	Symbol	Description	Simplified outline	Graphic symbol
1	D	drain		D
2	D	drain		
3	G	gate		G (A G A G A G A G A G A G A G A G A G
4	S	source	SC-74; TSOP6 (SOT457)	mbb076 S
5	D	drain		
6	D	drain		

6. Ordering information

Table 3. Ordering information

Type number	Package				
	Name	Description	Version		
PMN40SNA	SC-74; TSOP6	plastic, surface-mounted package (SC-74; TSOP6); 6 leads	SOT457		

7. Marking

Table 4. Marking codes

Type number	Marking code
PMN40SNA	н6

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8. Limiting values

Table 5. Limiting values

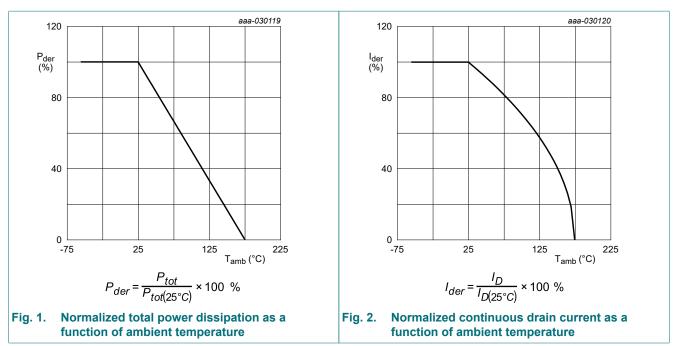
In accordance with the Absolute Maximum Rating System (IEC 60134).

Symbol	Parameter	Conditions		Min	Мах	Unit
V _{DS}	drain-source voltage	T _j = 25 °C		-	60	V
V _{GS}	gate-source voltage			-20	20	V
I _D	drain current	V _{GS} = 10 V; T _{amb} = 25 °C	[1]	-	4.7	А
		V _{GS} = 10 V; T _{amb} = 100 °C	[1]	-	3	А
I _{DM}	peak drain current	T_{amb} = 25 °C; single pulse; $t_p \le 10 \ \mu s$		-	19	А
P _{tot}	total power dissipation	T _{amb} = 25 °C	[2]	-	650	mW
			[1]	-	1.7	W
		T _{sp} = 25 °C		-	7.5	W
Tj	junction temperature			-55	175	°C
T _{amb}	ambient temperature			-55	175	°C
T _{stg}	storage temperature			-65	175	°C
Source-drain	n diode			I		
I _S	source current	T _{amb} = 25 °C	[1]	-	1.7	А
ESD maximu	um rating			I		_
V _{ESD}	electrostatic discharge voltage	НВМ	[3]	-	500	V
Avalanche r	uggedness					
E _{DS(AL)S}	non-repetitive drain- source avalanche energy	T _{j(init)} = 25 °C; I _D = 1 A; DUT in avalanche (unclamped)		-	30	mJ
		1				

[1] Device mounted on an FR4 Printed-Circuit Board (PCB), single-sided copper, tin-plated and mounting pad for drain 6 cm².

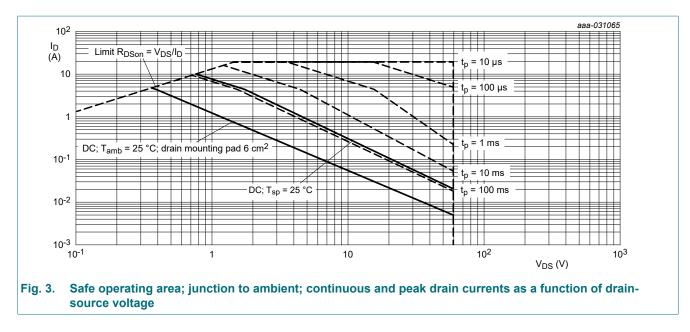
[2] Device mounted on an FR4 Printed-Circuit Board (PCB), single-sided copper, tin-plated and standard footprint.

[3] Measured between all pins.



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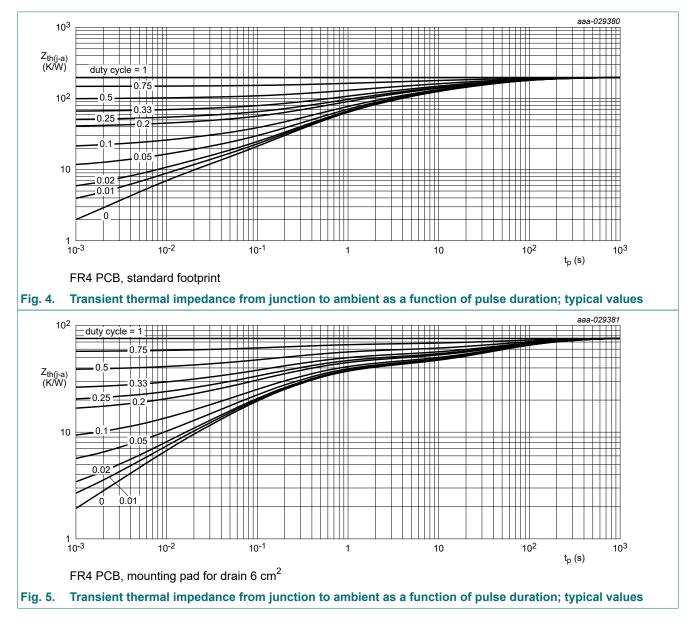


9. Thermal characteristics

Symbol	Parameter	Conditions		Min	Тур	Max	Unit
R _{th(j-a)} thermal resistance from	in free air	[1]	-	200	230	K/W	
	junction to ambient		[2]	-	78	90	K/W
R _{th(j-sp)}	thermal resistance from junction to solder point			-	15	20	K/W

[1] Device mounted on an FR4 PCB, single-sided copper, tin-plated and standard footprint.

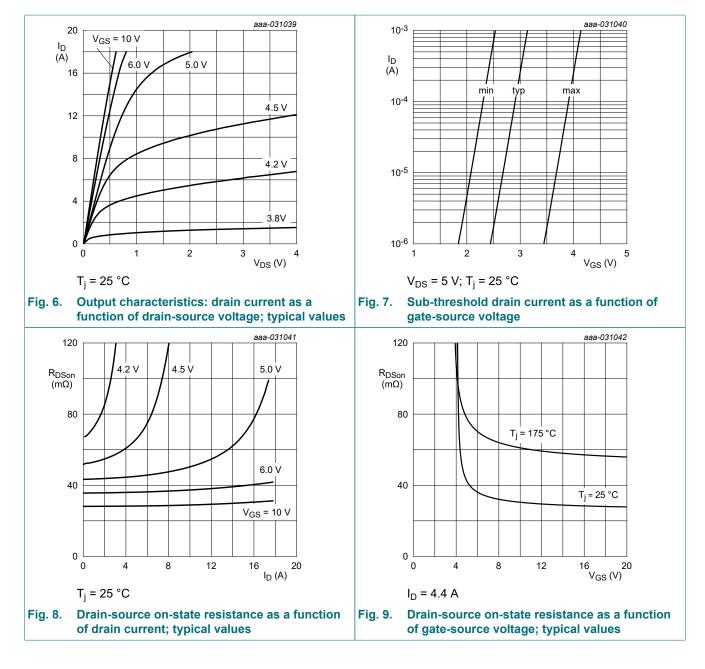
[2] Device mounted on an FR4 Printed-Circuit Board (PCB), single-sided copper, tin-plated and mounting pad for drain 6 cm².



10. Characteristics

Symbol	Parameter	Conditions	Min	Тур	Max	Unit
Static chara	octeristics					
V _{(BR)DSS}	drain-source breakdown voltage	I _D = 250 μA; V _{GS} = 0 V; T _j = 25 °C	60	-	-	V
V _{GSth}	gate-source threshold voltage	I _D = 250 μA; V _{DS} = V _{GS} ; T _j = 25 °C	2.4	3	4	V
I _{DSS}	drain leakage current	V _{DS} = 60 V; V _{GS} = 0 V; T _j = 25 °C	-	-	1	μA
I _{GSS}	gate leakage current	V _{GS} = 20 V; V _{DS} = 0 V; T _j = 25 °C	-	-	100	nA
		V _{GS} = -20 V; V _{DS} = 0 V; T _j = 25 °C	-	-	-100	nA
R _{DSon}	drain-source on-state	V _{GS} = 10 V; I _D = 4.7 A; T _j = 25 °C	-	29	36	mΩ
	resistance	V _{GS} = 10 V; I _D = 4.7 A; T _j = 175 °C	-	61	76	mΩ
9 _{fs}	forward transconductance	V _{DS} = 10 V; I _D = 4.4 A; T _j = 25 °C	-	8	-	S
R _G	gate resistance	f = 1 MHz	-	1.7	-	Ω
Dynamic ch	aracteristics	1	I			
Q _{G(tot)}	total gate charge	V_{DS} = 30 V; I_{D} = 4.4 A; V_{GS} = 10 V;	-	9	14	nC
Q _{GS}	gate-source charge	T _j = 25 °C	-	1.7	-	nC
Q _{GD}	gate-drain charge	1	-	2.8	-	nC
C _{iss}	input capacitance	V _{DS} = 30 V; f = 1 MHz; V _{GS} = 0 V;	-	453	-	pF
C _{oss}	output capacitance	T _j = 25 °C	-	62	-	pF
C _{rss}	reverse transfer capacitance		-	42	-	pF
t _{d(on)}	turn-on delay time	V_{DS} = 30 V; I _D = 4.2 A; V _{GS} = 10 V;	-	6	-	ns
t _r	rise time	$R_{G(ext)} = 6 \Omega; T_j = 25 °C$	-	7	-	ns
t _{d(off)}	turn-off delay time	1 [-	11	-	ns
t _f	fall time] [-	5	-	ns
Source-drai	n diode					
V _{SD}	source-drain voltage	I _S = 1.7 A; V _{GS} = 0 V; T _j = 25 °C	-	0.8	1.2	V
t _{rr}	reverse recovery time	I _S = 1.7 A; dI _S /dt = -100 A/μs;	-	12	-	ns
Q _r	recovered charge	V _{GS} = 0 V; V _{DS} = 30 V; T _j = 25 °C	-	6	-	nC

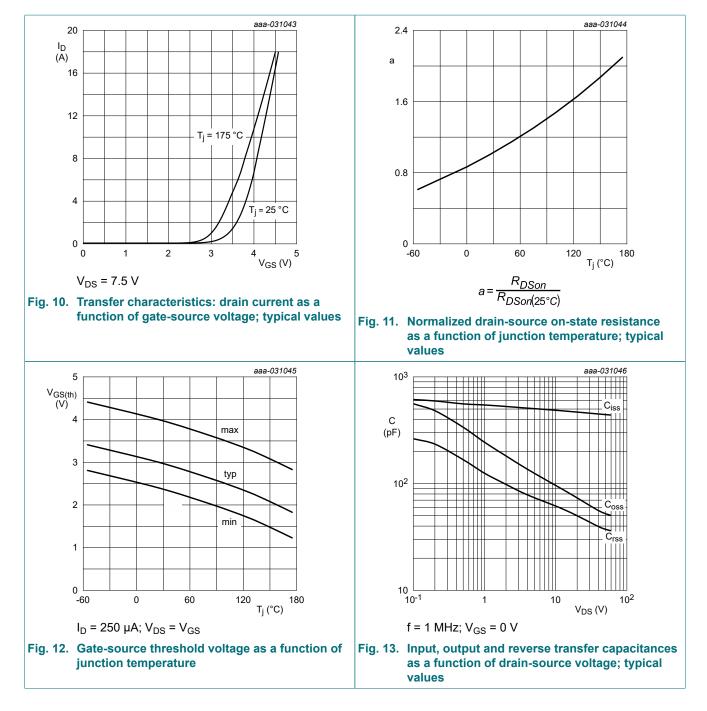
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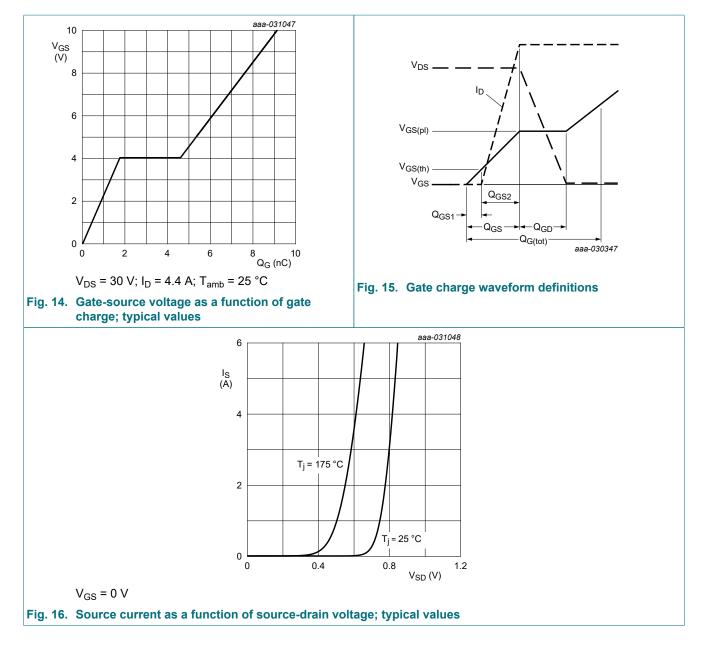
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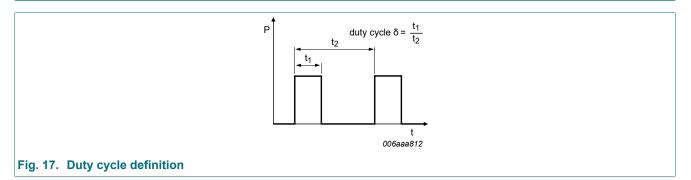
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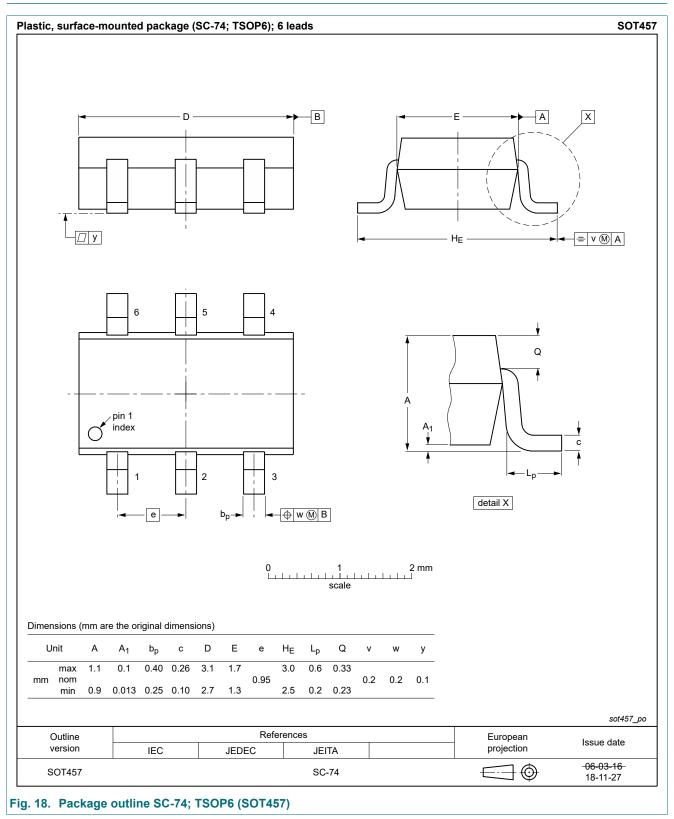
11. Test information



Quality information

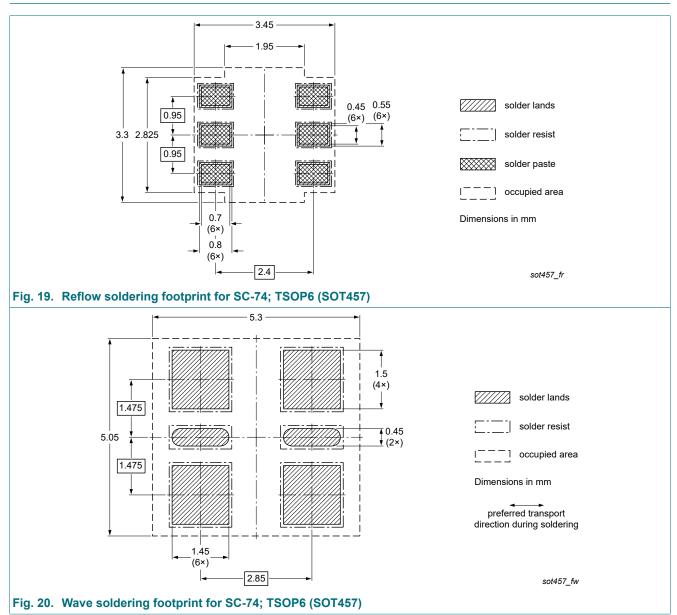
This product has been qualified in accordance with the Automotive Electronics Council (AEC) standard *Q101* - *Stress test qualification for discrete semiconductors*, and is suitable for use in automotive applications.

12. Package outline



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13. Soldering



Product data sheet

14. Revision history

Table 8. Revision history						
Data sheet ID	Release date	Data sheet status	Change notice	Supersedes		
PMN40SNA v.2	20210408	Product data sheet	-	PMN40SNA v.1		
Modifications:	Chapter "Limiting values": Typo correction at parameter P _{tot}					
PMN40SNA v.1	20200311	Product data sheet	-	-		

15. Legal information

Data sheet status

Document status [1][2]	Product status [3]	Definition
Objective [short] data sheet	Development	This document contains data from the objective specification for product development.
Preliminary [short] data sheet	Qualification	This document contains data from the preliminary specification.
Product [short] data sheet	Production	This document contains the product specification.

 Please consult the most recently issued document before initiating or completing a design.

[2] The term 'short data sheet' is explained in section "Definitions".

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